XO5162 Series

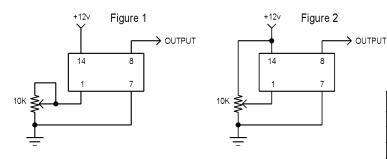
14 pin DIP, 5.0 Volt, Sinewave, OCXO

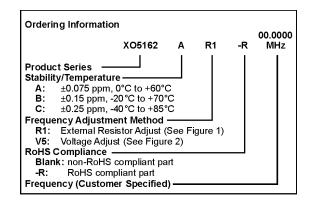






- Standard DIP/DIL package offering tight stabilities, fast warm-up, and low current
- Ideal for PCS base stations, cellular base stations, phase locking, and SAR/SAT applications
- 5V Operation

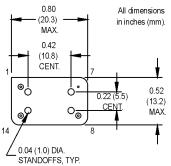




Pin Connections

PIN	FUNCTION
1	Frequency Adjust
7	Case ground & supply return
8	R.F. Output
14	Supply (+)

0.04 (1.0) TYP.
0.60 (15.2) CENT.
0.30 (7.6) MAX. 0.02 (0.5) DIA. 0.30 (7.6) CENT.
0.00



	PARAMETER	Symbol	Min.	Max.	Units	Condition
Electrical Specifications	Frequency Range	F	10	20	MHz	
	Operating Temperature	TA	(See Ordering Information)		°C	
	Stability Over Temperature	∆ F/F	(See Ordering Information)		ppm	
	Short Term Stability			5 x 10 ⁻¹¹		0.1 to 30 secs.
	Aging (First Year)			±0.7	ppm	
	Aging (10 Years)			±4.0	ppm	
	Frequency Vs. Supply			±0.1	ppm	
	Frequency Vs. Load			±0.01	ppm	
	Supply Voltage	Vcc	+4.8	+5.2	Volts	
	Warm-Up Time		To spec after 30 secs.			0°C
	Warm-Up Current			250	mΑ	After 10 secs.
	Supply Current	lcc		70	mA	+30°C
				110	mA	-20°C
	Output Signal		Sinewave			
	Output Level		1	2	V pk-pk	
	Harmonics		-10		dBc	
	Spurious Modes		-70		dBc	
	Output Load			1K ∐5 pF		+10%
	Frequency Adjustment (Pin 1)		± 4		ppm	See Figure 1 or 2
	Tuning Slope	Positiv		Positive		
	Input Impedance (Pin 1)		4.7K		ohms	
	Phase Noise					(BW = 1 Hz)
	1 Hz			-80	dBc/Hz	Offset from carrier
	10 Hz			-110	dBc/Hz	
	100 Hz			-135	dBc/Hz	
	1 kHz			-145	dBc/Hz	
	10 kHz			-150	dBc/Hz	
Environmental	Mechanical Shock	2000 g, 0.3 mS, 1/2 sine				
	Vibration	2000 Hz, 10 g				
	Storage Temperature	-55°C to +125°C				
	Hermeticity	Per MIL-STD-202, Method 112				
ធី Solderability EIAJ-STD-002						

MtronPTI reserves the right to make changes to the product(s) and service(s) described herein without notice. No liability is assumed as a result of their use or application.